



CMS Power-lines Protection Series (CMS-P)

Descriptions

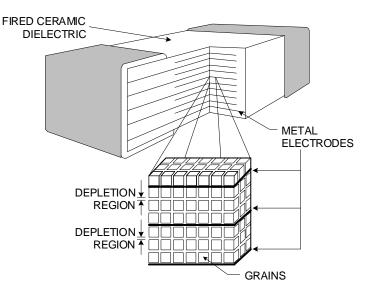
The Ceramic Micro-Surge Protection Device (CMS) is manufactured from semiconducting ceramics which offer rugged protection and excellent transient energy absorption in a small SMD package. These devices are designed to suppress a variety of transient events, including those speified in IEC61000-4-2, IEC61000-4-5 and other standards used for Electromagnetic Compliance (EMC).

These devices are available in ceramic leadless chip form, eliminating lead inductance and assuring fast speed of response to transient surges. In addition, The CMS transient suppressors have temperature independent suppression characteristics, affording protection from -55 $^{\circ}$ C to 125 $^{\circ}$ C, which is much better than suppressors based on silicon semiconductor technology.

The CMS-P Series is specially designed for power-lines protection applications. It features a very high current protection capability with a very small size, also a very fast response thus a ultra low clamping voltage. These characteristics make CMS-P Series devices the best replacement of TVS and metal oxide (MOV).

Features

- Multi-Layers Construction Provides Higher Power Dissipation
- Surge Current Capability: 1500A (@8/20µs)
- Better than UL94V-0 Flammability Rating
- No Temperature Derating up to 125°C Ambient
- Reliable ESD Protection up to 30kV acc. to IEC61000-4-2
- Inherent Bi-directional Clamping
- SMD type Body size 1210
- "Zero" Lead Inductance
- Very low Camping Voltage
- RoHS compliant



Multilayer Internal Construction



Order Information

Туре	Quantity	Reel Size
CMS1210	1500 pcs	7 Inch
	1500 pcs	(178mm)

Applications

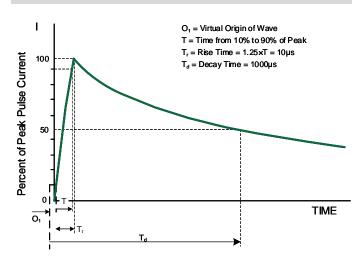
- Severe transient voltage suppressor for power-lines, replacing traditional MOV&TVS solutions.
- Surge protection for IEC61000-4-5
- EFT protection for IEC 61000-4-4 (Level 4)
- ESD protection for IEC 61000-4-2 (Level 4)



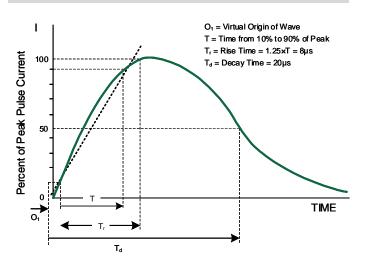
Device Ratings and Specifications (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Value	Unit
Maximum Continuous a.c. Voltage	V _{M(AC)}	50~60Hz	60	V
Maximum Continuous d.c. Voltage	V _{M(DC)}		85	V
Nominal Varistor Voltage	V _N	@1mA	90~110	V
Maximum Leakage Current	١L	@V _M	30	μA
Maximum Clamping Voltage	Vc	@lc	170	V
Class Current	lc	tp = 8/20µs	5	А
Peak Pulse Current	Ірр	tp = 8/20µs	1500	А
Rated Energy	Ем	10/1000µs	4	J
Typical Capacitance	С	1V _{RMS} ,1kHZ	1000	pF
Operating Temperature Range			-55 to +125	°C
Storage Temperature			-55 to +150	°C

Pulse Waveform - 10/1000µs waveform



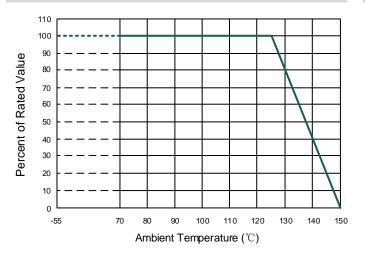
Pulse Waveform - 8/20µs waveform



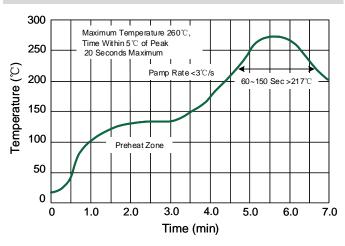




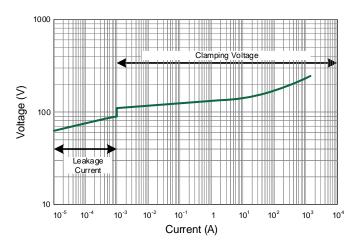
Current, Energy and Power Derating Curve



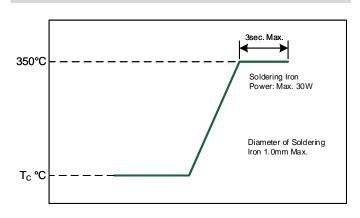
Lead-free Re-flow Solder Profile



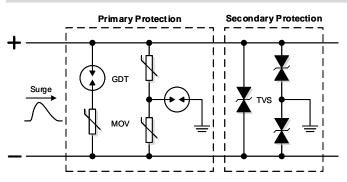
V/I characteristics



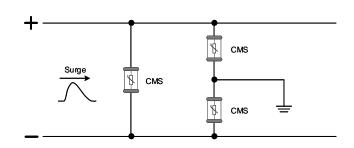
Iron Soldering Profile



Typical Applications



Traditional Solution of Surge Protection for Power Supply

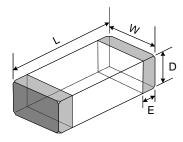


CMS Solution of Surge Protection for Power Supply

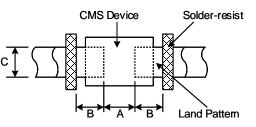




Product Dimensions



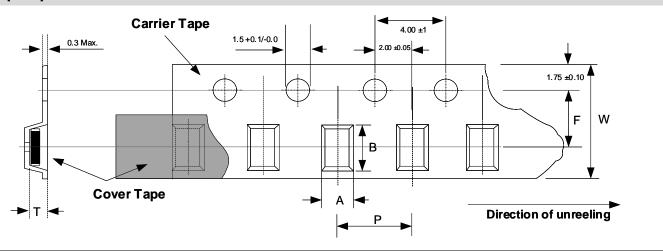
Product Dimensions



Recommended PCB Pattern

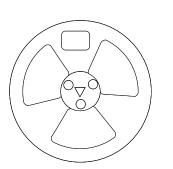
Size	L	w	D	E	Α	В	С
1210	3.2 +0.6/-0.20	2.5 +0.4/-0.20	2.60 Max.	0.25~0.75	1.9~2.5	1.2~1.6	2.6~3.0

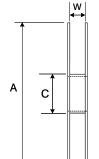
Tape Specifications



Туре	А	В	т	Р	W	D
CMS1210	2.85 ±0.10	3.50 ±0.10	2.85 Max.	4.00 ±0.10	8.00 ±0.20	3.50 ±0.05

Reel Dimension





Type	Spec.	D	imensions(mm)
Туре	Spec.	Α	w	С
CMS1210	7"*8mm	178	8.4+1.5/-0.0	58



Storage

- Storage temperature range (packaging conditions): -10°C~+40°C RH 70% (Max.).
- The solderability of the external electrode may be deteriorated if packages are stored where they are exposed to high humidity. Package must be stored at 40°C or less and 70% RH or less.
- The solderability of the external electrode may be deteriorated if packages are stored where they are exposed to dust of harmful gas (e.g. HCl, sulfurous gas of H₂S).
- Packaging material may be deformed if package are stored where they are exposed to heat of direct sunlight.
- Solderability shall be guaranteed for 12 months from the date of delivery on condition that they are stored at the environment specified in Clause 2. For those parts, which passed more than 12 months shall be checked solder-ability before use.

Item	Requirment	Test Condition
High Temperature Storage	 Breakdown voltage change: within ±10% No mechanical damage 	 Temperature: 150 ± 2°C Time: 1000 ± 2 hours Test after placing in ambient temperature for 24 hours
Low Temperature Storage	 Breakdown voltage change: within ±10% No mechanical damage 	 Temperature: -55± 2℃ Time: 1000 ± 2 hours Test after placing in ambient temperature for 24 hours
Thermal Shock	 Breakdown voltage change: within ±10% No mechanical damage 	 Temperature, Time: -55°C for 30±3 min→125°C for 30±3min. Transforming interval: 20sec. (Max.) Tested cycle: 100 cycles. The chip shall be stabilized at normal condition for 1~2 hours before measuring.
High Temperature Load	 Breakdown voltage change: within ±10% No mechanical damage 	 Temperature: 125 ± 2°C Rated working voltage applied Time: 1000 ± 2 hours Test after placing in ambient temperature for 24 hours
Damp Heat Load / Humidity Load	 Breakdown voltage change: within ±10% No mechanical damage 	 Temperature: 60 ± 2°C Humidity: 90-95% RH Rated working voltage applied Time: 1000 ± 2 hours Test after placing in ambient temperature for 24 hours

Environmental Reliability Test

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Website: www.boarden.com.cn Tel: 86-21-61401058 Fax: 86-21-61730538

Boarden Electronics Ltd.